

1 1. A method comprising:
2 forming a heat transfer fin of a laminate of two
3 different materials; and
4 permanently securing said fin to a heat
5 conductive base.

1 2. The method of claim 1 wherein forming said fin
2 includes forming a laminate of metallic and non-metallic
3 material.

1 3. The method of claim 1 including securing said
2 laminate to the base using crimping.

1 4. The method of claim 2 including adhesively
2 bonding said metallic and non-metallic materials.

1 5. The method of claim 1 wherein forming a heat
2 transfer fin includes forming a fin of a laminate of a
3 metallic and a pyrolytic graphite material.

1 6. The method of claim 1 including forming the fin
2 with an aspect ratio higher than 20:1.

1 7. The method of claim 5 including forming the fin
2 with an aspect ratio of 60:1.

1 8. The method of claim 1 including securing heat
2 transfer fin to an integrated circuit.

1 9. The method of claim 8 including securing said
2 heat transfer fin to a microprocessor.

1 10. The method of claim 2 including forming the
2 metallic and non-metallic material of equal thicknesses.

1 11. A heat sink comprising:
2 a heat sink fin including two different
3 materials; and
4 a conductive base, said fin secured to said base.

1 12. The heat sink of claim 11 wherein one of said
2 materials is metallic and the other is non-metallic.

1 13. The heat sink of claim 11 wherein said fin is
2 crimped to said base.

1 14. The heat sink of claim 12 wherein said metallic
2 and non-metallic materials are adhesively bonded.

1 15. The heat sink of claim 12 wherein said non-
2 metallic material is a pyrolytic graphite material.

1 16. The heat sink of claim 11 wherein the fin aspect
2 ratio is higher than 20:1.

1 17. The heat sink of claim 16 wherein the fin aspect
2 ratio is 60:1.

1 18. The heat sink of claim 11 wherein said base is
2 secured to an integrated circuit.

1 19. The heat sink of claim 18 wherein said integrated
2 circuit is a microprocessor.

1 20. The heat sink of claim 11, said fin including a
2 first sheet of metallic material and a second sheet of non-
3 metallic material, said sheets being laminated together.

1 21. The heat sink of claim 20 wherein said first and
2 second sheets are of equal thicknesses.

1 22. An integrated circuit comprising:
2 an integrated circuit chip; and
3 a heat sink secured to said chip, said heat sink
4 including a heat transfer fin of a laminate of metallic and
5 non-metallic material.

1 23. The circuit of claim 22 wherein said fin is
2 crimped to said base.

1 24. The circuit of claim 22 wherein said metallic and
2 non-metallic materials are adhesively bonded.

1 25. The circuit of claim 22 wherein said non-metallic
2 material is a pyrolytic graphite material.

1 26. The circuit of claim 22 wherein the fin aspect
2 ratio is higher than 20:1.

1 27. The circuit of claim 26 wherein the fin aspect
2 ratio is 60:1.

1 28. The circuit of claim 22 wherein said base is
2 secured to an integrated circuit.

1 29. The circuit of claim 28 wherein said integrated
2 circuit chip is a microprocessor.

1 30. The circuit of claim 22 wherein said metallic and
2 non-metallic material are of equal thicknesses.